

# FMMT591A SOT23 PNP silicon planar medium power transistor

## **Features**

Low equivalent on resistance  $R_{CE(sat)}$  = 350m $\Omega$  at 1A Part Marking Detail -91A Complementary type -FMMT491A

## Absolute maximum ratings.

Parameter	Symbol	Value	Unit
Collector-Base voltage	V <sub>CBO</sub>	-40	V
Collector-Emitter voltage	V <sub>CEO</sub>	-40	V
Emitter-Base voltage	V <sub>EBO</sub>	-5	V
Peak pulse current	I <sub>CM</sub>	-2	Α
Continuous Collector current	I <sub>C</sub>	-1	Α
Base current	I <sub>B</sub>	-200	mA
Power dissipation at Tamb=25oC	P <sub>tot</sub>	500	mW
Operating an storage temperature range	T <sub>j</sub> ; T <sub>STG</sub>	-55 to +150	°C

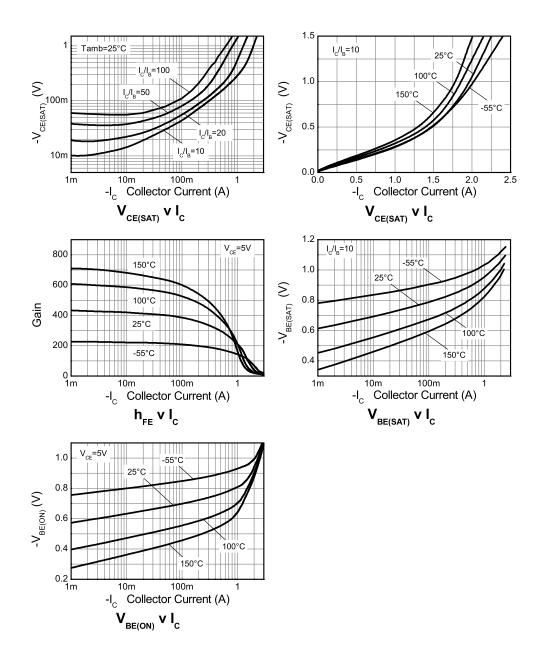
# Electrical characteristics (at $T_{amb} = 25$ °C)

Parameter	Symbol	Min	Max	Unit	Conditions
Collector-Base breakdown voltage	V <sub>(BR)CBO</sub>	-40		V	I <sub>C</sub> =-100μA
Collector-Emitter breakdown voltage	V <sub>(BR)CEO</sub>	-40		V	I <sub>C</sub> =-10mA <sup>(*)</sup>
Emitter-Base breakdown voltage	V <sub>(BR)EBO</sub>	-5		V	I <sub>E</sub> =-100μA
Collector cut-off current	I <sub>CBO</sub>		-100	nA	V <sub>CB</sub> =-30V
Emitter cut-off current	I <sub>EBO</sub>		-100	nA	V <sub>EB</sub> =-4V
Collector-Emitter cut-off current	I <sub>CES</sub>		-100	nA	V <sub>CES</sub> =-30V
Collector-Emitter saturation voltage	V <sub>CE(sat)</sub>		-0.2	V	I <sub>C</sub> =-100mA, I <sub>B</sub> =-1mA <sup>(*)</sup>
			-0.35	V	I <sub>C</sub> =-500mA, I <sub>B</sub> =-20mA <sup>(*)</sup>
			-0.5	V	I <sub>C</sub> =-1A, I <sub>B</sub> =-100mA <sup>(*)</sup>
Base-Emitter saturation voltage	V <sub>BE(sat)</sub>		-1.1	V	I <sub>C</sub> =-1A, I <sub>B</sub> =-50mA <sup>(*)</sup>
Base-Emitter turn-on voltage	V <sub>BE(on)</sub>		-1.0	V	I <sub>C</sub> =-1A, V <sub>CE</sub> =-5V <sup>(*)</sup>
Static forward current transfer ratio	h <sub>FE</sub>	300			I <sub>C</sub> =-1mA,
		300	800		I <sub>C</sub> =-100mA <sup>(*)</sup>
		250			I <sub>C</sub> =-500mA <sup>(*)</sup> , V <sub>CE</sub> =-5V
		160			I <sub>C</sub> =-1A <sup>(*)</sup>
		30			I <sub>C</sub> =-2A <sup>(*)</sup>
Transition frequency	f <sub>T</sub>	150		MHz	I <sub>C</sub> =-50mA, V <sub>CE</sub> =-10V
					f=100MHz
Output capacitance	C <sub>obo</sub>		10	рF	V <sub>CB</sub> =-10V, f=1MHz

#### NOTES:

(\*) Measured under pulse conditions. Pulse width=300 $\mu$ s. Duty cycle 2%

## **Electrical characteristics**



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